

### NOT RECOMMENDED FOR NEW DESIGN **USE DMP2110UQ**



## **Product Summary**

BVD	ss	Rds(on) max	Package	I <sub>D MAX</sub> Та = +25°С	
001	$110m\Omega @ V_{GS} = -4.5V$		0.0.700	-2.6A	
-20	V	225mΩ @ V <sub>GS</sub> = -2.5V	SOT23	-2.0A	

## Description

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- General purpose interfacing switches
- Power management functions

#### P-CHANNEL ENHANCEMENT MODE MOSFET

### Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMP2225LQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

## **Mechanical Data**

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Deekere	Packing			
Part Number	Package	Qty.	Carrier		
DMP2225LQ-7	SOT23	3,000	Tape & Reel		

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information



2P2 = Product Type Marking Code YM = Date Code Marking

Y = Year (ex: J = 2022)

M = Month (ex: 9 = September)

#### Date Code Kev

Date Obde Rey												
Year	2019		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	G		J	K	L	М	Ν	0	Р	R	S	Т
	-											
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteri	stic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	V	
Gate-Source Voltage			Vgss	±12	V
Continuous Drain Current (Note 5)Steady State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		ID	-2.6 -2	A	
Pulsed Drain Current (Note 6)			IDM	-8	А

# **Thermal Characteristics**

Symbol	Value	Unit
PD	1.08	W
R <sub>0JA</sub>	115	°C/W
TJ, TSTG	-55 to +150	0°
	PD Reja	PD 1.08 Reja 115

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

						7 ( 0 )	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	-20	—		V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS		—	-800	nA	$V_{DS} = -20V, V_{GS} = 0V$	
On-State Drain Current	Id(on)	-6 -3	_		A	$V_{DS} \le -5V, V_{GS} = -4.5V$ $V_{DS} \le -5V, V_{GS} = -2.5V$	
Gate-Source Leakage	Igss	_		±80	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						•	
Gate Threshold Voltage	VGS(TH)	-0.45	—	-1.25	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)		80 165	110 225	mΩ	$V_{GS} = -4.5V, I_D = -2.6A$ $V_{GS} = -2.5V, I_D = -2.0A$	
Forward Transfer Admittance	Y <sub>fs</sub>		4		S	$V_{DS} = -2.5V, I_D = -2.6A$	
Diode Forward Voltage (Note 6)	Vsd			-1.26	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -2.6A	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	Ciss		250	—	pF		
Output Capacitance	Coss	_	88	—	pF	Vps = -10V, Vgs = 0V f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	58	—	pF		
Gate Resistance	Rg	—	12	16	Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	4.3	5.3			
Gate-Source Charge	Qgs	_	0.9	_	nC	V <sub>GS</sub> = -4.5V, V <sub>DS</sub> = -10V, I <sub>D</sub> = -2.7A	
Gate-Drain Charge	Qgd	_	2.1	_		10 = -2.7  A	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Repetitive rating, pulse width limited by junction temperature.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:











## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)					
С	2.0					
Х	0.8					
X1	1.35					
Y	0.9					
Y1	2.9					



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